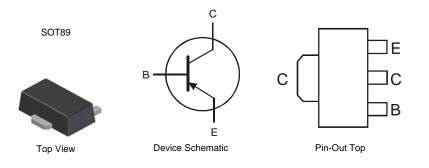


Features

- Ultra Low Collector-Emitter Saturation Voltage
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Weight: 0.055 grams (approximate)



Ordering Information (Note 3)

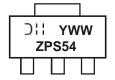
Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DSS5540X-13	ZPS54	13	12mm	2,500

Notes: 1. No purposefully added lead.

2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com

3. For packaging details, please go to our website at http://www.diodes.com

Marking Information



ZPS54 = Product Type Marking Code) | | = Manufacturer's Code Marking YWW = Date Code Marking Y = Last digit of year (ex: 8 = 2008) WW = Week code (01 - 53)



Maximum Ratings @T_A = 25°C unless otherwise specified

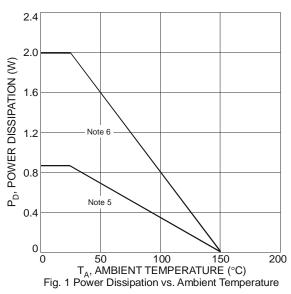
Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	-40	V	
Collector-Emitter Voltage	V _{CEO}	-40	V	
Emitter-Base Voltage	V _{EBO}	-6	V	
Peak Pulse Collector Current	I _{CM}	-10	А	
Repetitive Peak Pulse Collector Current (Note 4)	I _{CRP}	-5	А	
Continuous Collector Current	Ι _C	-4	А	
Peak Pulse Base Current	I _{BM}	-2	А	
Continuous Base Current	IB	-1	А	

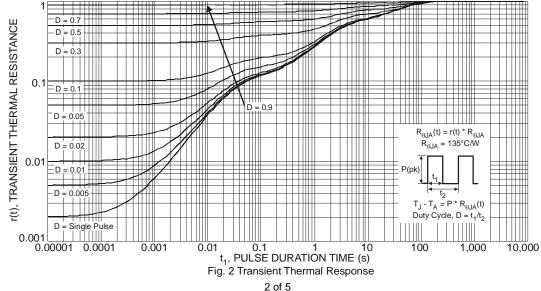
Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5) @ $T_A = 25^{\circ}C$	PD	0.9	W
Thermal Resistance, Junction to Ambient Air (Note 5) @ $T_A = 25^{\circ}C$	$R_{\theta JA}$	139	°C/W
Power Dissipation (Note 6) @ $T_A = 25^{\circ}C$	PD	2	W
Thermal Resistance, Junction to Ambient Air (Note 6) @ $T_A = 25^{\circ}C$	$R_{\theta JA}$	62.5	°C/W
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	°C

Notes:

Pulse width ≤ 10ms; Duty cycle ≤ 0.2
Device mounted on FR-4 PCB with minimum recommended pad layout.
Device mounted on FR-4 PCB with 1inch² copper pad layout.



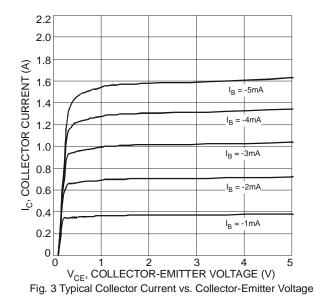


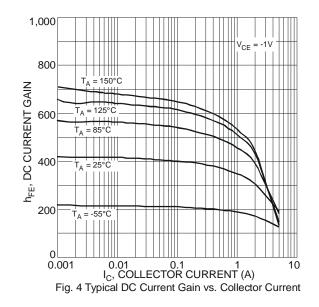


Electrical Characteristics @T_A = 25°C unless otherwise specified

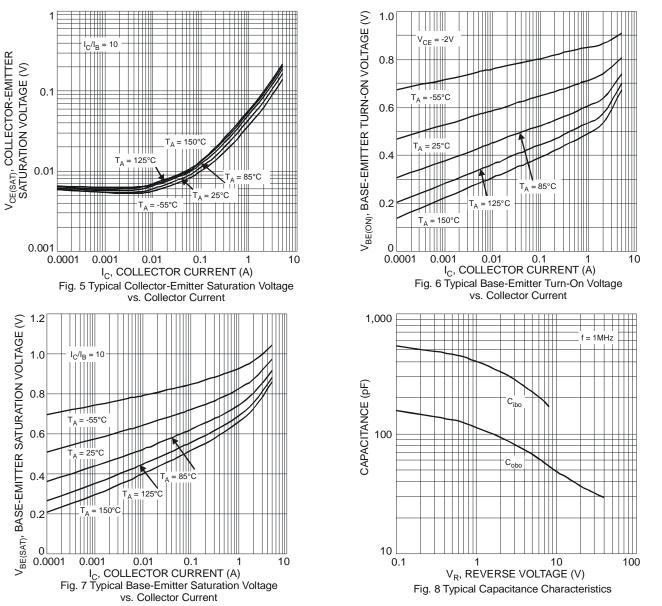
			_			
Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Collector-Base Breakdown Voltage	BV _{CBO}	-40	_	_	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 7)	BV _{CEO}	-40	—	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-6			V	$I_E = -100 \mu A$
Collector-Base Cutoff Current	1	_		-100	nA	$V_{CB} = -30V, I_E = 0$
	I _{CBO}	_		-50	μΑ	$V_{CB} = -30V, I_E = 0, T_A = 150^{\circ}C$
Emitter-Base Cutoff Current	I _{EBO}	_		-100	nA	$V_{EB} = -5V, I_C = 0$
		250				$V_{CE} = -2V, I_{C} = -0.5A$
DC Current Gain (Note 6)	h	200	350			$V_{CE} = -2V, I_{C} = -1A$
DC Current Gain (Note 6)	h _{FE}	150 —				$V_{CE} = -2V, I_{C} = -2A$
		50	_			$V_{CE} = -2V, I_C = -5A$
			_	-120		I _C = -0.5A, I _B = -5mA
			_	-170		$I_{\rm C} = -1A, I_{\rm B} = -10mA$
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	_	-70	-160	mV	I _C = -2A, I _B = -200mA
		_	-165	-340		I _C = -4A, I _B = -200mA
		_	-150	-375		I _C = -5A, I _B = -500mA
Equivalent On-Resistance	R _{CE(sat)}		-30	-75	mΩ	I _C = -5A, I _B = -500mA
Base-Emitter Saturation Voltage	V _{BE(sat)}			-1.1	V	I _C = -4A, I _B = -200mA
Base-Emilier Saturation Voltage		_		-1.2		I _C = -5A, I _B = -500mA
Base-Emitter Turn-on Voltage	V _{BE(on)}	_		-1.0	V	$V_{CE} = -2V, I_{C} = -2A$
Transition Frequency	f _T	60			MHz	V _{CE} = -10V, I _C = -0.1A, f = 100MHz
Collector Capacitance	Cc	_		105	pF	$V_{CB} = -10V, I_E = 0A, f = 1MHz$
Turn-On Time	t _{on}		63	_	ns	
Delay Time	t _d		15		ns	
Rise Time	tr		48		ns	$V_{CC} = -10V, I_{C} = -2A,$
Turn-Off Time	t _{off}		280		ns	$I_{B1} = -I_{B2} = -200 \text{mA}$
Storage Time	ts		232		ns]
Fall Time	t _f	_	48		ns]

Notes: 7. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$.

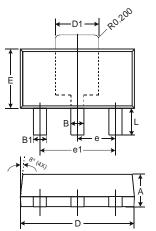


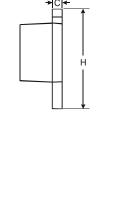






Package Outline Dimensions

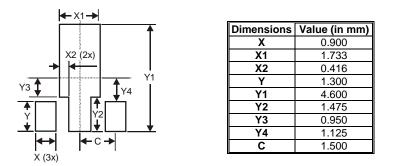




SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.43		
D	4.40	4.60		
D1	1.52	1.83		
Е	2.29	2.60		
е	1.50 Typ			
e1	3.00 Typ			
Н	3.94	4.25		
L	0.89	1.20		
All Dimensions in mm				



Suggested Pad Layout



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